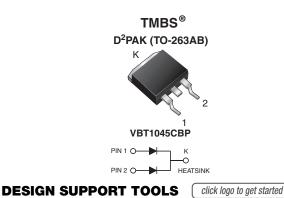
Vishay General Semiconductor

## Trench MOS Barrier Schottky Rectifier for PV Solar Cell Bypass Protection

Ultra Low  $V_F = 0.34$  V at  $I_F = 2.5$  A



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3D Models

Models Available

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 5.0 A			
V <sub>RRM</sub>	45 V			
I <sub>FSM</sub>	100 A			
V <sub>F</sub> at I <sub>F</sub> = 5.0 A	0.41 V			
T <sub>OP</sub> max. (AC mode)	150 °C			
$T_J$ max. (DC forward current)	200 °C			
Package	D <sup>2</sup> PAK (TO-263AB)			
Circuit configurations	Common cathode			

#### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation



HALOGEN

FREE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- T<sub>J</sub> 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

#### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

#### Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER			VBT1045CBP	UNIT			
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	45	V			
Maximum average forward rectified current (fig. 1)	per device	I (1)	10	А			
	per diode	I <sub>F(AV)</sub> <sup>(1)</sup>	5				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			100	А			
Operating junction and storage temperature range (AC mode)			-40 to +150	°C			
Junction temperature in DC forward current without reverse bias, $t \leq 1 \ h$			≤ 200	°C			

Notes

(1) With heatsink

<sup>(2)</sup> Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	SYMBOL	TYP.	MAX.	UNIT			
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.44	-	- V		
	I <sub>F</sub> = 5.0 A			0.49	0.58			
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.34	-			
	I <sub>F</sub> = 5.0 A			0.41	0.50			
Reverse current per diode	V <sub>B</sub> = 45 V	$T_{A} = 25 \text{ °C}$ $T_{A} = 125 \text{ °C}$	I <sub>R</sub> <sup>(2)</sup>	-	500	μA		
	v <sub>R</sub> = 43 v			5	15	mA		

Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

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<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	SYMBOL VBT1045CBP		
Turning thermal registering	per diode	$R_{ extsf{ heta}JC}$	3.5	°C/W	
Typical thermal resistance	per device		2.5	0/10	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT1045CBP-M3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VBT1045CBP-M3/8W	1.38	8W	800/reel	Tape and reel	

#### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

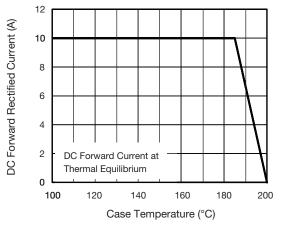


Fig. 1 - Maximum Forward Current Derating Curve

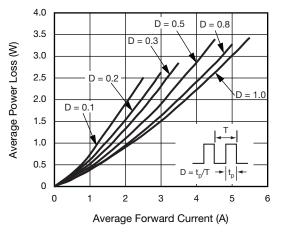
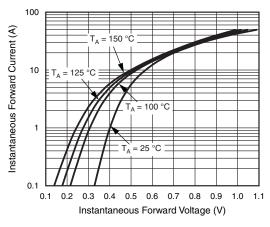


Fig. 2 - Forward Power Loss Characteristics Per Diode





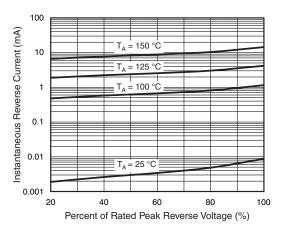
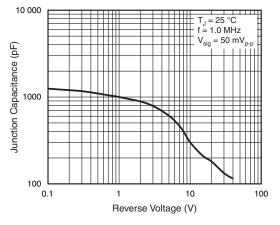


Fig. 4 - Typical Reverse Characteristics Per Diode

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Fig. 5 - Typical Junction Capacitance Per Diode

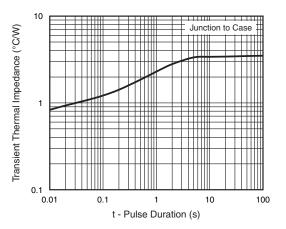
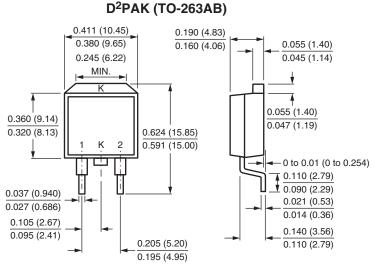
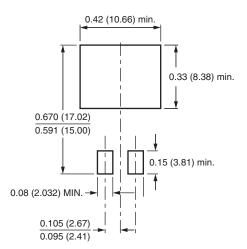


Fig. 6 - Typical Transient Thermal Impedance Per Diode

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



#### **Mounting Pad Layout**





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